

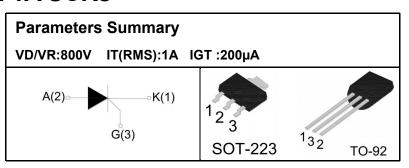
S0102 1A SCRs

FEATURES

- Sensitive gate
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

APPLICATIONS

- Ground Fault Circuit Interrupters (GFCI)
- General purpose switching and phase control
- Ignition circuits, CDI
- Motor control e.g. small kitchen appliances









ABSOLUTE MAXIMUM RATINGS						
Parameter	Symbol	Value	Unit			
Storage junction temperature range	Tstg	-40 ~150	°C			
Operating junction temperature range	Tj	-40~125	°C			
repetitive surge peak Off-state voltage	$ m V_{DRM}$	800	V			
repetitive peak reverse voltage	$ m V_{RRM}$	800	V			
RMS on-state current (TC=75°C)	$I_{T(RMS)}$	1.0	A			
Non repetitive surge peak on-state current (180° conduction angle, F=50Hz, t=10ms/60Hz, 8. 3ms)	I_{TSM}	12	A			
I ² t value for fusing (tp=10ms)	I ² t	0.72	A ² S			
Critical rate of rise of on-state current $(I = 2 \times IGT, tr \le 100 \text{ ns})$	di/dt	50	A/μS			
Peak gate current	I_{GM}	0.5	A			
Average gate power dissipation	$P_{G(AV)}$	0.1	W			
Maximum device temperature for solderingPurposes (for 10 seconds maximum)	$T_{\rm L}$	260	°C			
ESD level	HBM	Class 3 (4000-16000V)				
Humidity sensitive level	MSL	Three-level (30°C, 60%RH, 168h)				

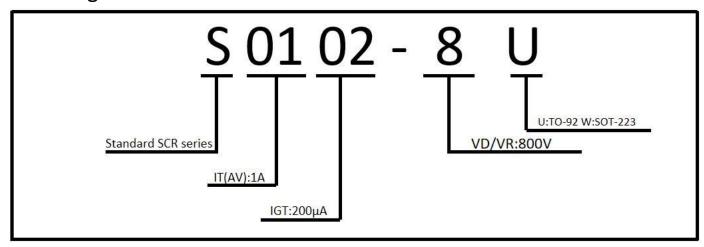
Thermal Resistances							
Symbol Parameter			Value	Unit			
Rth(j-c) Ju	Junction to case (DC)	TO-92	70	°C/W			
		SOT-223	25	C/W			



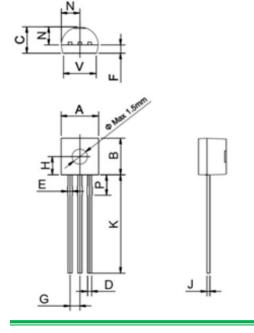
ELECTRICAL CHARACTERISTICS (T=25°Cunless otherwise specified)							
Symbol	Test Condition		Unit				
		MIN.	TYP.	MAX.	Unit		
I_{GT}	$V = 12V R = 140\Omega$		40	120	μΑ		
V_{GT}			-	1.0	V		
V_{GD}	$V_D = V_{DRM} Tj = 125^{\circ}C R = 1K\Omega$		1	_	V		
$I_{\rm L}$	$I_G=1.2I_{GT}$	_	_	6	mA		
I_{H}	IT=50mA		_	5	mA		
dV/dt	V _D =2/3V _{DRM} Gate Open Tj=125°C	50	_	_	V/µs		

STATIC CHARACTERISTICS						
Symbol	Parameter	Value(MAX.)	Unit			
V_{TM}	ITM =2.0A tp=380μs	Tj =25°C	1.7	V		
I_{DRM}	$V_{\mathrm{D}}\!\!=\!\!V_{\mathrm{DRM}}V_{\mathrm{R}}\!\!=\!\!V_{\mathrm{RRM}}$	Tj =25°C	10	μΑ		
I_{RRM}		Tj =125°C	0.5	mA		

Ordering Information Scheme



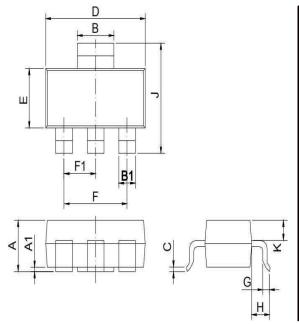
TO-92 Package Mechanical Data



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур-	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
В	4.32		5.33	0.170		0.210
С	3.18		4.19	0.125		0.165
D	0.254		0.506	0.016		0.021
Е	0.30		0.70	0.024		0.031
F		1.30			0.051	-
G		1.27			0.050	-
Н		2.30			0.091	-
J	0.30		0.50	0.011		0.020
K	12.70		15.0	0.500		0.591
N	2.04		2.66	0.080		0.105
P	1.86		2.06	0.073		0.081
V			4.50			0.169



SOT-223 Package Mechanical Data



	I		D:			
Ref.		Millimeters		nsions	Inches	
	Min. Typ- Max.			Min. Typ. Max.		
	IVIIII.	1 yp-	IVIAA.	IVIIII.	ryp.	IVIAX.
A	1.5	1.6	1.8	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
В	2.9	3.0	3.1	0.114	0.118	0.122
B1	0.6	0.7	0.8	0.024	0.028	0.031
С	0.22	0.26	0.32	0.009	0.010	0.013
D	6.3	6.5	6.7	0.248	0.256	0.264
Е	3.3	3.5	3.7	0.130	0.138	0.146
F		4.6			0.181	
F1		2.3			0.091	
G	0.7	0.9	1.1	0.028	0.035	0.043
Н	1.5	1.75	2	0.059	0.069	0.079
J	6.7	7.0	7.3	0.264	0.276	0.287
K		0.9			0.035	

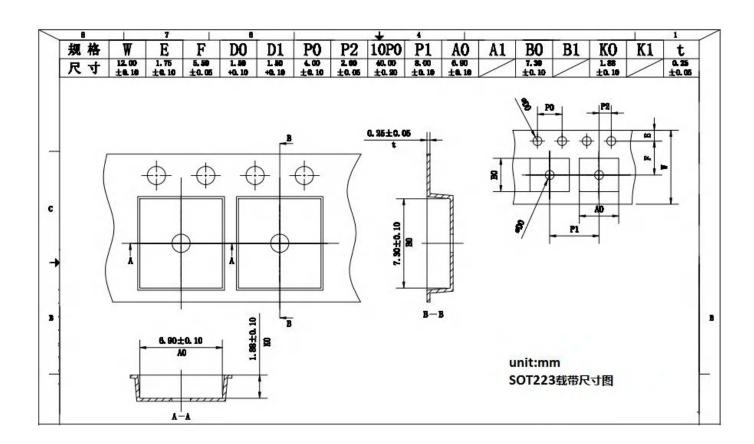




FIG.1 Maximum power dissipation versus Average on-state current

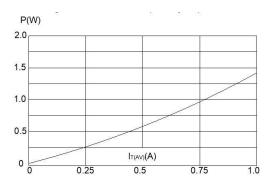


FIG.3: Surge peak on-state current versus number of cycles

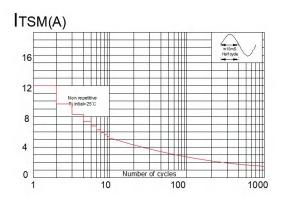


FIG.5: Non-repetitive surge peak on-state currentfor a sinusoidal pulse with width tp<10ms, and corresponding value of 12 t (dI/dt < $50A/\mu s$)

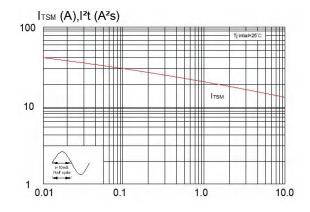


FIG.2: on-state current versus case temperature

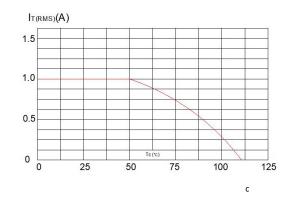


FIG.4: On-state characteristics (maximum values)

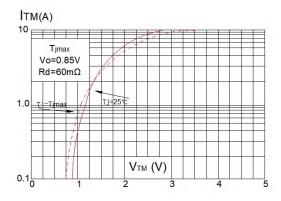
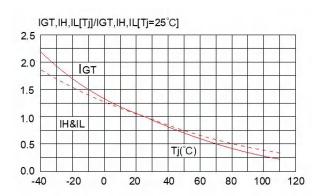


FIG.6: Relative variations of gate trigger current holding current and latching current versus junction temperature





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